



TITLE: A SILICIDED BURIED BITLINE PROCESS FOR A NON-VOLATILE MEMORY CELL

INVENTOR(S): Daniel Sobek, Timothy J. Thurgate, Mark W. Randolph

USSN: 09/885,426 Attorney Docket # AMD-E306

1 / 5

# Replacement Sheet

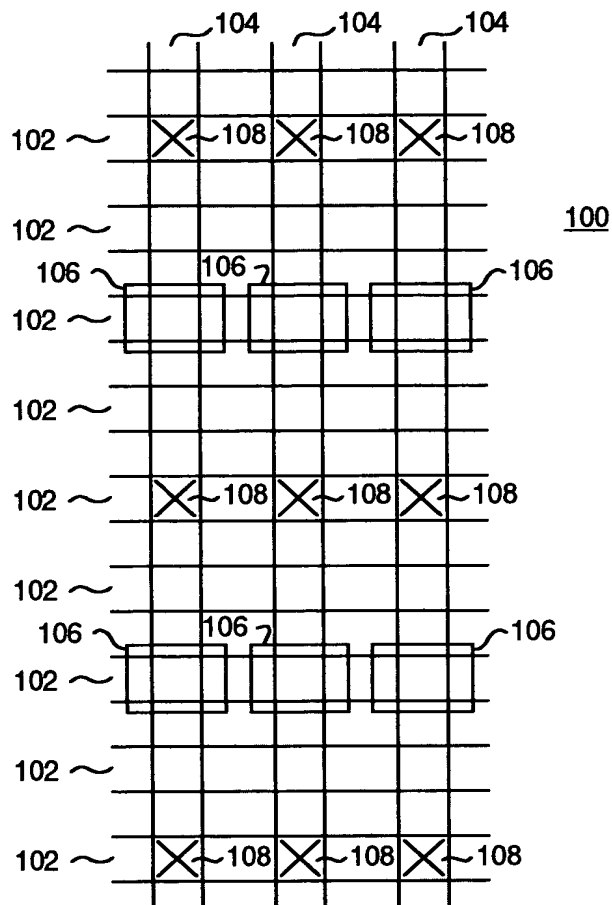


FIG. 1

PRIOR ART

2 / 5  
Replacement Sheet

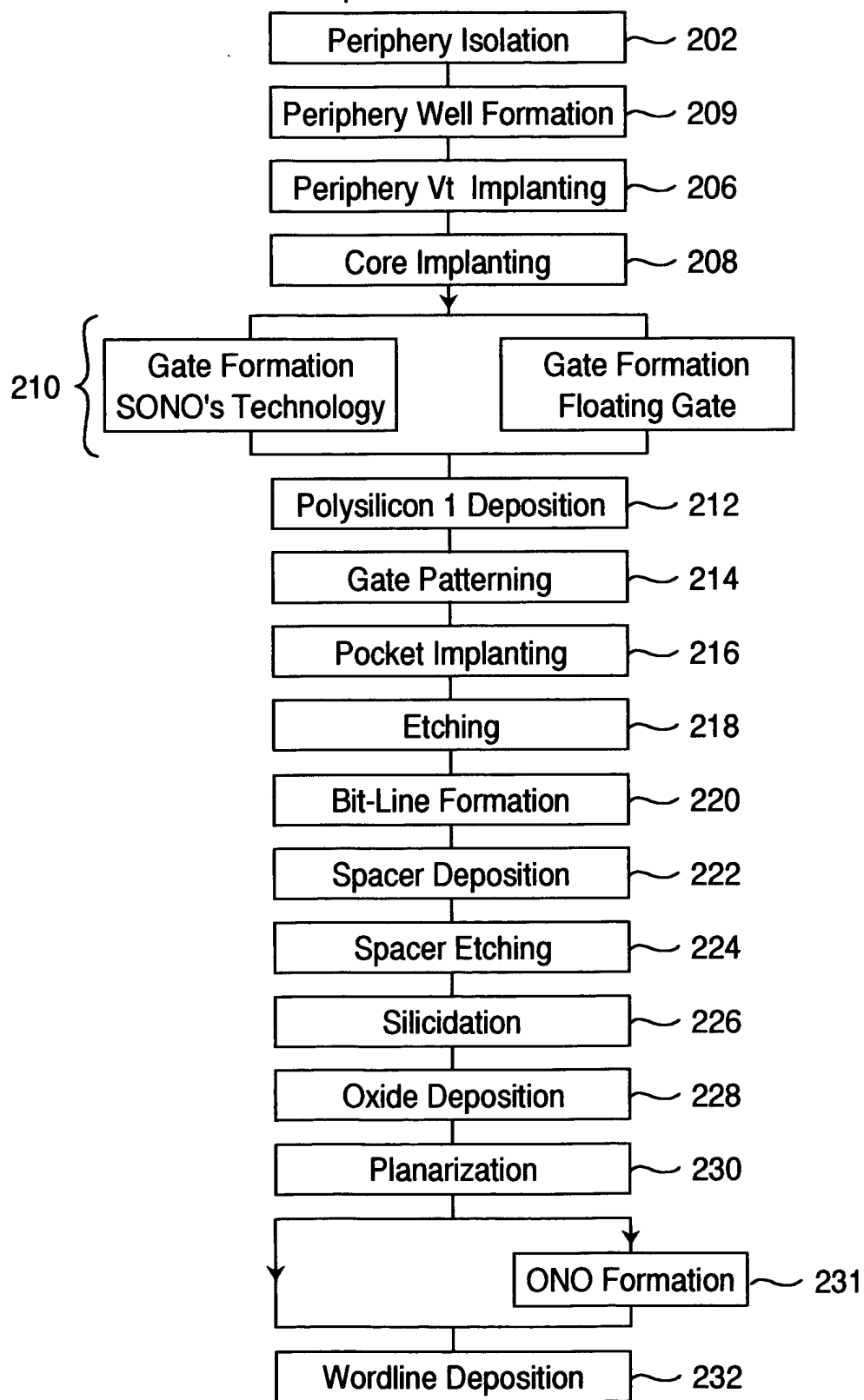


FIG. 2

3 / 5

Replacement Sheet

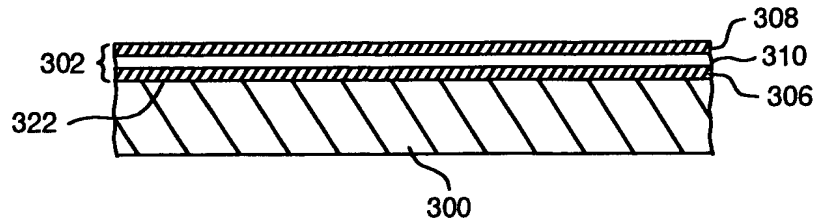


FIG. 3

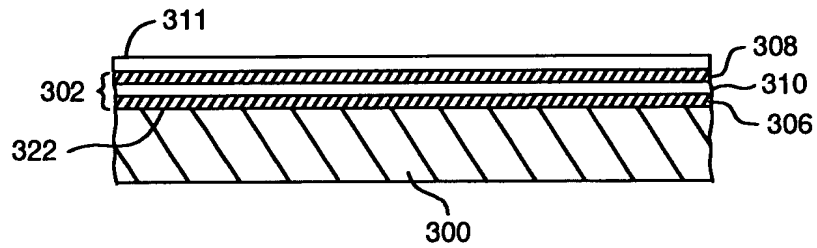


FIG. 4

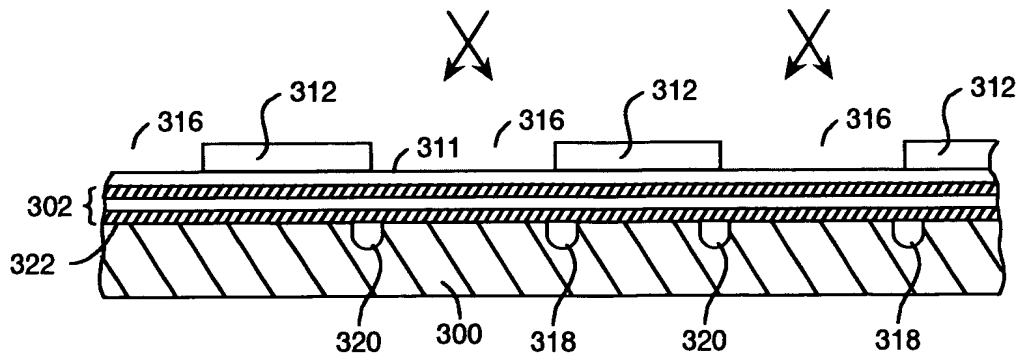


FIG. 5

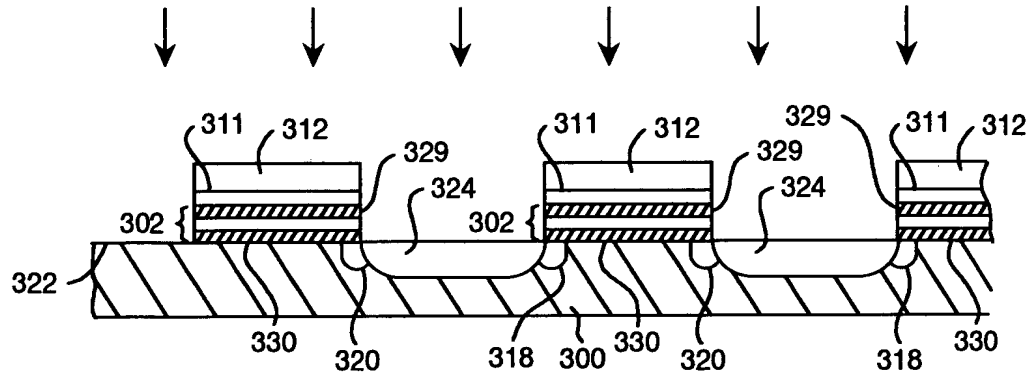


FIG. 6

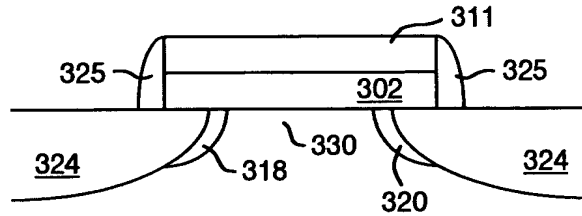


FIG. 7

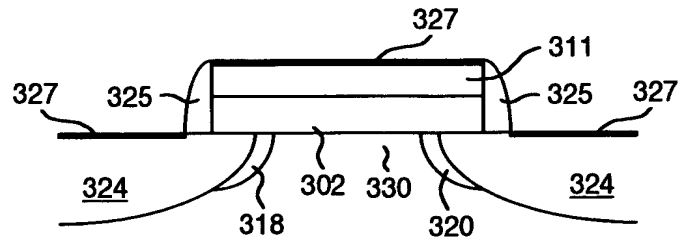


FIG. 8

5 / 5

Replacement Sheet

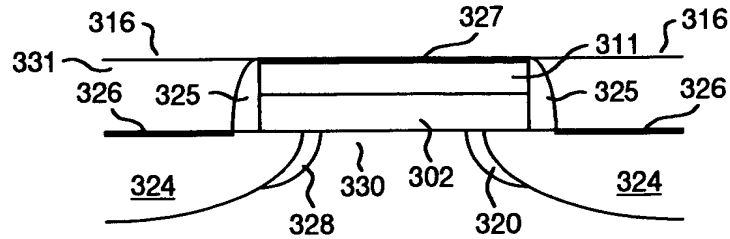


FIG. 9

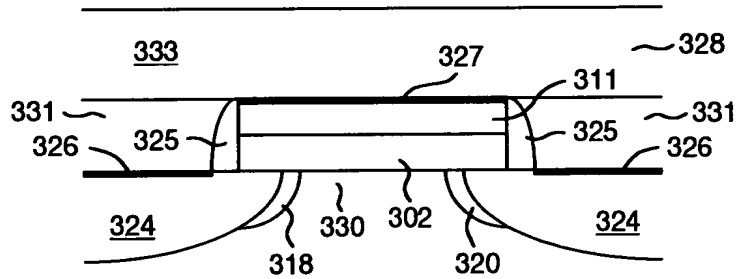


FIG. 10

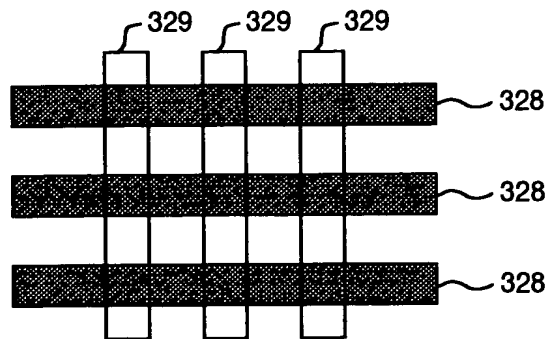


FIG. 11